### SY88422L



### 4.25Gbps Laser Driver with Integrated Bias

### **General Description**

The SY88422L is a single 3.3V supply, small form factor laser driver for telecom/datacom applications up to 4.25Gbps. The driver can deliver modulation current up to 90mA and a bias current up to 100mA.

Datasheets and support documentation can be found on Micrel's web site at: www.micrel.com.

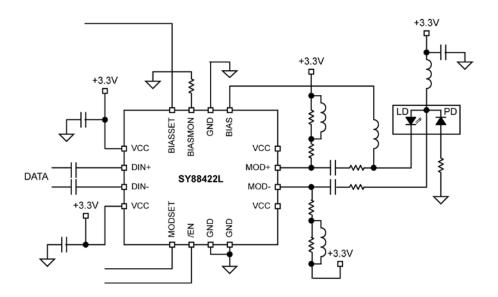
#### **Features**

- 35mA power supply current typical
- Operation up to 4.25Gbps
- · Modulation current up to 90mA
- Bias current up to 100mA
- Available in 16-pin small form factor (3mm x 3mm) QFN package

### **Applications**

- Multi-rate LAN, MAN applications up to 4.25Gbps: FC, GbE, SONET/SDH
- SFF, SFP, LX-4 Modules

### **Typical Application**



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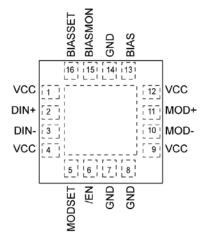
# Ordering Information<sup>(1)</sup>

| Part Number                 | Package<br>Type | Operating<br>Range | Package Marking                      | Lead Finish    |
|-----------------------------|-----------------|--------------------|--------------------------------------|----------------|
| SY88422LMG                  | QFN-16          | Industrial         | 422L with Pb-Free bar-line indicator | NiPdAu Pb-Free |
| SY88422LMGTR <sup>(2)</sup> | QFN-16          | Industrial         | 422L with Pb-Free bar-line indicator | NiPdAu Pb-Free |

#### Notes:

- 1. Contact factory for die availability. Dice are guaranteed at  $T_A = +25$ °C, DC Electricals only.
- 2. Tape and Reel.

# **Pin Configuration**



16-Pin QFN

SY88422L Micrel, Inc.

## **Pin Description**

| Pin Name    | Pin Number | Pin Function  |
|-------------|------------|---|
| 1, 4, 9, 12 | VCC        | Supply Voltage. Bypass with a 0.1μF//0.01μF low ESR capacitor as close to VCC pin as possible.  |
| 7, 8, 14    | GND        | Ground. Ground and exposed pad must be connected to the plane of the most negative potential.   |
| 2           | DIN+       | Non-inverting input data. Internally terminated with $50\Omega$ to a reference voltage.   |
| 3           | DIN-       | Inverting input data. Internally terminated with $50\Omega$ to a reference voltage.   |
| 5           | MODSET     | Modulation current setting and control. The voltage applied to this pin will set the modulation current. Input impedance $25k\Omega$ .      |
| 6           | /EN        | Active Low TTL. The driver is disabled when this pin is unconnected or /EN asserted high. The driver is enabled when /EN is asserted low.   |
| 10          | MOD-       | Inverted modulation current output. Outputs modulation current when input data is negative.   |
| 11          | MOD+       | Non-inverted modulation current output. Outputs modulation current when input data is positive.   |
| 13          | BIAS       | BIAS Current Output   |
| 15          | BIASMON    | Bias monitor. Install an external resistor from this pin to GND to convert the output current to a voltage proportional to the bias current |
| 16          | BIASSET    | Bias current setting. The voltage applied to this pin will set the bias current. Input impedance $25k\Omega$ .                              |

## **Truth Table**

| DIN+ | DIN- | /EN     | MOD+ <sup>(1)</sup> | MOD- | Laser Output <sup>(2)</sup> |  |
|------|------|---------|---------------------|------|-----------------------------|--|
| L    | Н    | L       | Н                   | L    | L                           |  |
| Н    | L    | L       | L                   | Н    | Н                           |  |
| X    | Х    | H or NC | Н                   | L    | L                           |  |

#### Notes:

- 1.  $I_{MOD} = 0$  when MOD+ = H.
- 2. Assuming that the laser cathode is tied to MOD+.

## Absolute Maximum Ratings<sup>(1)</sup>

| 0.5V to +4.0V                    |
|----------------------------------|
| $V_{CC}$ -1.2V to $V_{CC}$ +0.5V |
| 0V to V <sub>CC</sub>            |
| ec.)+260°C                       |
| 65°C to +150°C                   |
|                                  |

## Operating Ratings<sup>(2)</sup>

| Supply Voltage (V <sub>CC</sub> )         | +3.0V to +3.6\ |
|---|----------------|
| Ambient Temperature (T <sub>A</sub> )     | 40°C to +85°C  |
| Package Thermal Resistance <sup>(3)</sup> |                |
| QFN                                       |                |
| (θ <sub>JA</sub> ) Still-air              | 60°C/W         |
| (WIB)                                     | 33°C/W         |

#### **DC Electrical Characteristics**

 $T_A = -40^{\circ}\text{C}$  to +85°C and  $V_{CC} = +3.0\text{V}$  to +3.6V, unless otherwise noted. Typical values are  $V_{CC} = +3.3\text{V}$ ,  $T_A = 25^{\circ}\text{C}$ ,  $I_{MOD} = 30\text{mA}$ ,  $I_{BIAS} = 20\text{mA}$ .

| Symbol                     | Parameter                                       | Condition                             | Min                  | Тур | Max               | Units     |
|----------------------------|---|---------------------------------------|----------------------|-----|-------------------|-----------|
| I <sub>CC</sub>            | Power Supply Current                            | Modulation currents excluded          |                      | 35  | 56 <sup>(4)</sup> | mA        |
| V <sub>MOD_C</sub>         | Compliance Voltage                              |                                       | V <sub>CC</sub> -1.5 |     | Vcc               | V         |
| V <sub>BIAS_C</sub>        | Compliance Voltage                              |                                       | V <sub>CC</sub> -2.3 |     | Vcc               | V         |
| R <sub>IN(DATA)</sub>      | Input Resistance at DIN+, DIN-,<br>Single Ended |                                       | 45                   | 50  | 55                | Ω         |
| V <sub>DIFF_IN</sub> (DIN) | Differential Input Voltage Swing                |                                       | 100                  |     | 2400              | $mV_{pp}$ |
| V <sub>IL</sub> (/EN)      | Input Low Voltage                               |                                       |                      |     | 0.8               | V         |
| V <sub>IH</sub> (/EN)      | Input High Voltage                              |                                       | 2                    |     |                   | V         |
| R <sub>IN (MODSET)</sub>   | MODSET Input Resistance                         |                                       |                      | 25  |                   | kΩ        |
| V <sub>MODSET</sub>        | Voltage Range on MODSET Pin                     | I <sub>MOD</sub> range 10mA to 90mA   |                      |     | 1.2               | V         |
| R <sub>IN (BIASSET)</sub>  | BIASSET Input Resistance                        |                                       |                      | 25  |                   | kΩ        |
| V <sub>BIASSET</sub>       | Voltage Range on BIASSET Pin                    | I <sub>BIAS</sub> range 10mA to 100mA |                      |     | 1.2               | V         |

#### Notes:

<sup>1.</sup> Permanent device damage may occur if absolute maximum ratings are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to absolute maximum ratings conditions for extended periods may affect device reliability.

<sup>2.</sup> The data sheet limits are not guaranteed if the device is operated beyond the operating ratings.

Package Thermal Resistance assumes exposed pad is soldered (or equivalent) to the devices most negative potential on the PCB. ψ<sub>JB</sub> uses a 4-layer and θ<sub>JA</sub> in still air unless otherwise stated.

<sup>4.</sup>  $I_{CC} = 56mA$  for worst-case conditions with  $I_{MOD} = 90mA$  and BIAS=100 mA,  $T_A = +85^{\circ}C$ ,  $V_{CC} = 3.6V$ .

#### **AC Electrical Characteristics**

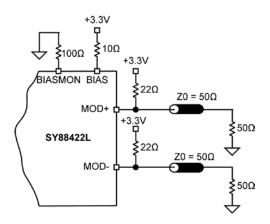
 $T_A = -40^{\circ}\text{C}$  to +85°C and  $V_{CC} = +3.0\text{V}$  to +3.6V, unless otherwise noted. Typical values are  $V_{CC} = +3.3\text{V}$ ,  $T_A = 25^{\circ}\text{C}$ ,  $I_{MOD} = 30\text{mA}$ ,  $I_{BIAS} = 20\text{mA}$ .

| Symbol                | Parameter                         | Condition  | Min | Тур | Max  | Units |
|-----------------------|-----------------------------------|--|-----|-----|------|-------|
|                       | Data Rate                         | NRZ  | 0.1 |     | 4.25 | Gbps  |
| I <sub>MOD</sub>      | Modulation Current <sup>(5)</sup> | Laser or equivalent load AC-coupled to the driver    | 10  |     | 90   | mA    |
| I <sub>MOD_OFF</sub>  | Modulation OFF Current            | Current at MOD+ and MOD- when the device is disabled |     |     | 150  | μА    |
| t <sub>r</sub>        | Output Current Rise Time          | 20% to 80%, 15 Ω load                                |     | 50  | 70   | ps    |
| t <sub>f</sub>        | Output Current Fall Time          | 20% to 80%, 15 Ω load                                |     | 50  | 70   | ps    |
|                       | Total Jitter                      |  |     |     | 20   | pspp  |
| I <sub>BIAS</sub>     | Bias Current <sup>(5)</sup>       |  | 5   |     | 100  | mA    |
| I <sub>Bias_OFF</sub> | Bias OFF Current                  | Current at BIAS when the device is disabled          |     |     | 150  | μА    |

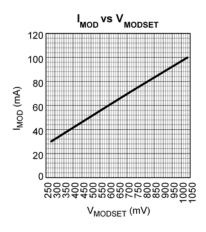
#### Notes:

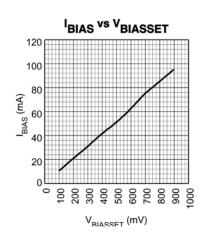
5. Load = 15Ω.

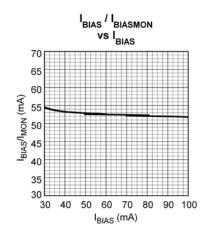
### **Test Circuit**



## **Typical Characteristics**

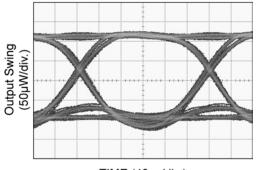






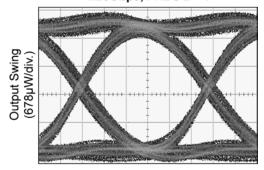
### **Functional Characteristics**

Electrical Eye Diagram 4.25Gbps, PRBS 2<sup>23</sup>-1, 25Ω load, 60mA Modulation



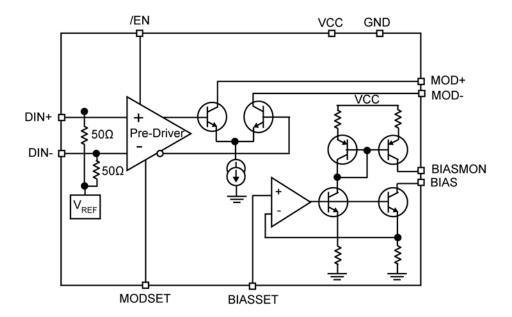
TIME (40ps/div.)

Optical Eye Diagram 4.25Gbps, PRBS 2<sup>23</sup>-1



TIME (40ps/div.)

## **Functional Block Diagram**



## **Input and Output Stages**

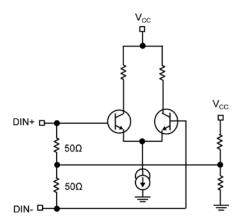


Figure 1a. Simplified Input Stage

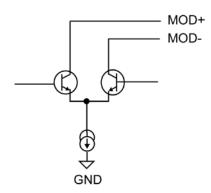


Figure 1b. Simplified Output Stage

## **Interfacing the Input to Differential Logic Drivers**

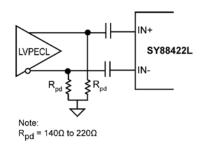


Figure 2a. AC-Coupling to LVPECL Driver

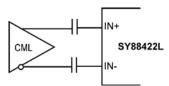


Figure 2b. AC-Coupling to CML Driver

#### **Application Hints**

The typical applications drawing on the front page shows how to connect the driver to the laser differentially. To drive the laser single ended, just disconnect MOD- from the laser anode and pull it up to  $V_{\rm CC}$  with a resistor equal to the equivalent resistor of the load on MOD+, damping resistor plus the laser equivalent resistor. Differential drive improves transition time and laser response. Driving the laser differentially will also minimize the cross talk with the rest of the circuitry on the board especially the receiver.

If we refer to Figure 3, the modulation current out of the driver is split between the pull-up network and the laser. If, for example, the total pull-up resistor is twice the sum of the damping resistor and laser equivalent series resistance, only two thirds (2/3) of the modulation current will be used by the laser. To keep most of the modulation current going through the laser, try to keep the total pull-up resistors as high as possible. One solution consists in using an inductor alone as pull-up, presenting a high impedance path for the modulation

current and zero ohm  $(0\Omega)$  path for the DC current offering headroom for the driver equal to  $V_{CC}$  and almost all the modulation current goes into the laser. The inductor alone will cause signal distortion, and, to improve that, a combination of resistor and inductor can be used as shown in Figure 3. In this case, the headroom of the driver is VCC - R1 \*  $\alpha I_{mod}$ , where  $\alpha I_{mod}$  is the portion of the modulation current that goes through the pull-up network.

The coupling capacitor creates a low-frequency cutoff in the circuit, and its value must be chosen to accommodate the lowest and the highest data rates. If the value of the cap is too high, it will degrade the performance at higher data rates, and, if its value is too small, it won't be able to hold a constant charge between the first bit and the last bit of a long string of identical bits in a low data rate application. This leads in both cases to higher pattern-dependant jitter in the transmitter signal.  $0.01\mu$ -to- $0.1\mu$ F is found to be good range for all applications from 155Mbps to 4.25Gbps.

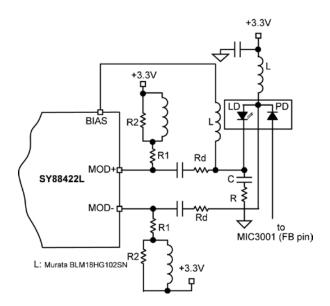
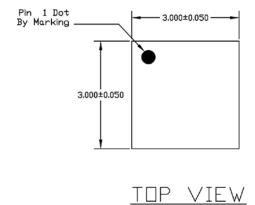
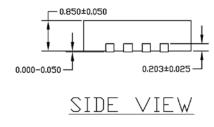
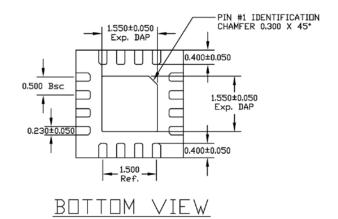


Figure 3. AC-Coupling the Laser to the Driver

### **Package Information**







#### NOTE

- ALL DIMENSIONS ARE IN MILLIMETERS.

  MAX. PACKAGE WARPAGE IS 0.05 mm.

  MAXIMUM ALLOWABE BURRS IS 0.076 mm IN ALL DIRECTIONS.

  PIN #1 ID ON TOP WILL BE LASER/INK MARKED.

16-Pin QFN

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